

EEE 205/ ECE205 Electronic Circuit I

EEE 205L/ECE205L Electronic Circuit I Laboratory – v3

EEE 206/ECE206 Electronic Circuit I Laboratory (1.5 credits) – v1, v2

A. Course General Information:

Course Code:	EEE 205
	EEE 205L
Course Title:	Electronic Circuit I
	Electronic Circuit I Laboratory
Credit Hours (Theory + Laboratory):	3 + 1
Contact Hours (Theory + Laboratory):	3 + 3
Category:	Program Core
Type:	Required, Engineering, Lecture + Laboratory
Prerequisites:	EEE 203 Electrical Circuit II
	EEE 203L Electrical Circuit II Laboratory
Co-requisites:	None
Equivalent Course	ECE 205 Electronic Circuit I
	ECE 205L Electronic Circuit I Laboratory
	EEE 206 Electronic Circuit I Laboratory (1.5 credits) – v1, v2
	ECE 206 Electronic Circuit I Laboratory (1.5 credits) – v1, v2

B. Course Catalog Description (Content):

Fundamental concepts of the semiconductor: electrons and holes, concept of doping, acceptors and donors, p and n-type materials. PN junction Diode and circuits: Operation principle, Current-Voltage characteristics, Diode models, diode large-signal analysis (DC analysis), Diode AC analysis: Rectifier Circuits-Half wave/Full wave, rectifier with filter capacitors, Clipper and Clamper circuits. Zener diode: IV characteristics, zener shunt regulator.

Metal-Oxide-Semiconductor Field-Effect-Transistor (MOSFET): structure and physical operation of MOSFETs, Threshold voltage, I-V characteristics, Types of MOSFET: NMOS, PMOS and CMOS. MOS large signal model. Large signal analysis of MOSFET circuits. MOSFET biasing circuits for various configurations and load line analysis, small signal analysis of MOSFET amplifier: AC equivalent circuits, small signal model, Analysis of various configurations, voltage and current gain, input and output impedance. MOSFET as switch. Basic logic circuits using MOSFET and CMOS.

Bipolar Junction Transistor (BJT): Basic structure, BJT region of operation, BJT Currents, BJT Terminal Voltages, BJT configurations and BJT I-V characteristics. BJT large signal models, large signal analysis of BJT circuits. Bipolar Junction Transistor Biasing: The dc load line and bias point, biasing the BJT for discrete circuits. small signal equivalent circuit models and small signal analysis of BJT amplifiers.

C. Rationale of the Course:

1. This course is considered as the backbone to modern technology. Electronic devices such as Diodes, Transistors are the essential building blocks for all the electronic systems that encompass our life everywhere and every moment. The rationale of the course is to enable the students to develop the fundamental knowledge of electronic devices, its operation. As one of the core courses for the EEE program, the knowledge from the course will be applied in almost all the future EEE courses such as Electronic Devices-2, Power electronics, Digital Electronics, Robotics etc.

D. Course Objective:

The objectives of this course are to

- a. Introduce the fundamental concepts of semiconductor materials and their properties required to understand the construction of electronic devices.
- b. Provide the students with the knowledge of the construction, operation principles, characteristics of the basic electronic devices (Diode, BJT, MOSFET etc.), and subsequently, with the ability to represent those devices into equivalent circuit models (large signal and small signal).
- c. Teach the students different methods to Analyze electronic circuits consisting of electronic devices: Diodes, BJTs and MOSFETs for DC and AC signals.
- d. Expose the students with the introductory design process of Amplifier circuits.
- e. Provide the students with the skills to simulate electronic circuits and construct, troubleshoot/debug them, and finally, extract experimental data with a view to solidifying the underlying knowledge of the devices.

E. Course Outcomes (COs):

Upon successful completion of this course, students will be able to

SI.	CO Description
CO1	Apply large signal equivalent circuit models of Diode and BJT to solve electronic circuits.
CO2	Solve electronic circuits consisting of different electronic devices such as diodes, BJT, MOSFETs for both DC and AC signals.
CO3	Design various electronic circuits employing different electronic devices.
CO4	Investigate the effect of different circuit parameters including load resistance on the Amplifier performances in terms of Gain, input/output impedance, faithful reproducibility, stability in biasing etc.
CO5	Use simulation tool to construct electronic circuits and simulate in schematic level

F. Mapping of Course Outcomes (COs) with Program Outcomes (POs):

COs	PO-a	PO-b	РО-с	PO-d	РО-е	PO-f	PO-g	PO-h	PO-i	РО-ј	PO-k	PO-I
CO1	~											
CO2	✓											
CO3			~									
CO4				~								

	CO5					✓							
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G. Mapping of CO-PO-Taxonomy Domain & Level-Delivery-Assessment Tool:

SI.	CO Description	POs	Bloom's taxonomy domain/level	Delivery methods and activities	Assessment tools
EEE 205	Electronic Circuit I				
CO1	Apply large signal equivalent circuit models of Diode and BJT to solve electronic circuits.	а	Cognitive/ Apply	Lectures, notes	Assignment, Quiz, Exam
CO2	Solve electronic circuits consisting of different electronic devices such as diodes, BJT, MOSFTEs for both DC and AC signals.	а	Cognitive/ Apply	Lectures, notes	Assignment, Quiz, Exam
CO3	Design various electronic circuits employing different electronic devices.	С	Cognitive/ Create	Lectures, notes	Assignment, Exam, Project
EEE 205	L Electronic Circuit I Laboratory				
CO4	Investigate the effect of different circuit parameters including load resistance on the Amplifier performances in terms of Gain, input/output impedance, faithful reproducibility, stability in biasing etc.	d	Cognitive/ Evaluate, Psychomotor/ Manipulation	Lectures, notes	Open-ended Lab Experiment
CO5	Use simulation tool to construct electronic circuits and simulate in schematic level	е	Cognitive/ Apply Psychomotor/ Manipulation	Lab class	Lab Work, Software Exam

Mapping of CO - PO Indicators - Knowledge Profile

CO No.	PO No.	Applicable PO Indicator	Knowledge Profile
CO1	а	a1, a4	K1, K3
CO2	а	a1, a4.	K1, K3
CO3	С	c1, c4	K5
CO4	d	d1, d2, d3, d4,d5	K2, K3, K5
CO5	е	e3	K6

Description of PO Indicators

PO Description	Indicator Description
(a) (Engineering knowledge: Apply knowledge of mathematics, natural science, (electrical and electronic / electronic and communication) engineering fundamentals, and specialization to the solution of complex (electrical and electronic / electronic and communication) engineering problems. (K1 to K4)	a1. Understand the concepts of mathematics, science and engineering knowledge required to solve complex electrical and electronic engineering problems a4. Apply fundamental and specialized engineering knowledge to solve complex electrical and electronic engineering problems

(c) Design/ development of solutions: Design solutions for complex (electrical and electronic / electronic and communication) engineering problems and design systems, components or processes that meet specified needs with appropriate consideration for public health and safety, cultural, societal, and environmental considerations. (K5)	c1. Define specifications, analyze technical requirements and constraints of the system/subsystem, component or process for the solutions of complex engineering problem. c4. Evaluate whether the design solutions meet the desired need.
(d) Investigation: Conduct investigations of complex (electrical and electronic / electronic and	d1. Design and set up experiments.
communication) engineering problems using research-based knowledge (K8) and research	d2. Conduct experiments and perform measurements.
methods including design of experiments, analysis and	d3.Detect the experimental faults and troubleshoot them.
interpretation of data, and synthesis of information to provide valid	d4. Analyze and Interpret data, graph, charts etc.
conclusions.	d5. Synthesize the information and findings obtained through research and/or experiments to reach valid conclusions
(e) Modern tool usage: Create, select and apply appropriate techniques, resources, and modern engineering and IT tools, including prediction and modelling, to complex (electrical and electronic / electronic and communication) engineering problems, with an understanding	e3. Use appropriate modern engineering, IT including modelling and simulation tools and techniques to develop and evaluate the solution of complex engineering problems.

Description of Applicable Knowledge Profiles

of the limitations. (K6).

K1	Natural Sciences	A systematic, theory-based understanding of the natural sciences applicable to the discipline
K2	Mathematics	Conceptually based mathematics, numerical analysis, statistics and the formal aspects of computer and information science to support analysis and modeling applicable to the discipline
K3	Engineering fundamentals	A systematic, theory-based formulation of engineering fundamentals required in the engineering discipline
K5	Engineering design	Knowledge that supports engineering design in a practice area
K6	Engineering practice	Knowledge of engineering practice (technology) in the practice areas in the engineering discipline

H. Course plan specifying content, COs, co-curricular activities (if any), teaching learning and assessment strategy mapped with COs:

Class	Topic	Teaching-Learning	Assessment	Corresponding
Week		Strategy	Strategy	COs
1	Fundamental concepts of the semiconductor: electrons and holes, concept of doping, acceptors and donors, p and n-type materials.	Lecture, Notes,		
2	PN junction Diode, Operation principle, Current-Voltage characteristics, Diode models, diode large-signal analysis (DC analysis)	Lecture, Notes, Pre- recorded video lectures, Tutorials.		CO1, CO2
3	Diode AC analysis: Rectifier Circuits-Half wave/Full wave, Clipper and Clamper circuits.	Lecture, Notes, Pre- recorded video lectures, Tutorials, Exam script checking sessions.	Quiz, Assignment, Midterm exam.	CO2
4	Rectifier with filter capacitors, Zener diode: IV characteristics, voltage regulator.	Lecture, Notes, Pre- recorded video lectures	Quiz, Assignment, Midterm exam.	CO2
5	MOSFET: Basic Structure, Operation Principle, Region of operation, Types of MOSFET: NMOS, PMOS and CMOS, I-V characteristics.	Lecture, Notes, Tutorials, Exam script checking sessions.	Quiz, Assignment Midterm Exam	
6	MOS large signal model. Large signal (DC) analysis of MOSFET circuits.	Lecture, Notes, Tutorials, Exam script checking sessions.	Quiz, Assignment Midterm Exam	CO2
7	MOSFET as switch. Basic logic circuits using MOSFET and CMOS.MOSFET biasing circuits for various configurations, loadline analysis,	Lecture, Notes, Tutorials, Exam script checking sessions.	Quiz, Assignment, Final Exam	CO2
8	Concept of amplification using MOSFET amplifier. Small signal analysis of MOSFET amplifier: AC equivalent circuits, small signal model, Analysis of various configurations, voltage and current gain, input and output impedance.	Lecture, Notes, Tutorials, Exam script checking sessions.	Quiz, Assignment Final Exam	CO2, CO3

9	Bipolar Junction Transistor (BJT): Basic structure, BJT region of operation, BJT Currents, BJT Terminal Voltages, BJT configurations and BJT I-V characteristics.	Lecture, Notes, Tutorials, Exam script checking sessions.		
10	BJT large signal models, BJT DC circuit Analysis.Switching operation of BJT circuit.	Lecture, Notes, Tutorials, Exam script checking sessions.	Quiz, Assignment Final Exam	CO1, CO2
11	BJT load line analysis, biasing the BJT for discrete circuits and biasing stability. small signal equivalent circuit models.	Lecture, Notes, Tutorials, Exam script checking sessions.	Quiz, Final Exam	CO2
12	BJT small signal analysis: Single- stage BJT amplifier circuits and their configurations, Amplifier design.	Lecture, Notes.	Quiz, Final Exam, Design Assignment	CO2, CO3

Laboratory:

	Topic	Week #	Related CO
1	Investigation of I-V characteristics of PN junction diode (Hardware)	Week 1	
2	Implementation of Half-wave/Full-wave rectifier circuits (Hardware)	Week 2	
3	Implementation of Clipper & Clamper network (Hardware)	Week 3	
4	Investigation of Zener diode IV characteristics and Implementation of voltage regulator circuit (Hardware)	Week 4	
5	Simulation of experiment 2-5 using PSpice Software	Week 5	CO5
6	Investigation of I-V characteristics of MOSFET (Hardware)	Week 6	
7	Implementation of Common Source MOSFET Amplifier Circuits (Hardware)	Week 7	
8	Investigation of I-V characteristics of BJT (Hardware)	Week 8	
9	Implementation and study of BJT Biasing Circuits (Hardware)	Week 9	
10	Implementation of Common Emitter BJT Amplifier Circuits (Hardware)	Week 10	CO4
11	Simulation I-V characteristics of BJT, BJT Biasing Circuits, Common Emitter BJT Amplifier Circuits using PSpice Software (Software)	Week 11	CO5
12	Software exam	Week 12	
13	Hardware exam	Week 13	

I. Learning Materials:

SI	Title	Author(s)	Publication Year	Edition	Publisher	ISBN
1	Microelectronics circuits	Adel S. Sedra, Kenneth C. Smith	2014	7 th ed.	Oxford University Press	ISBN-13: 978- 0199339136
2	Microelectronics Circuit Analysis & Design	Donald A. Neaman	2010	4 th ed.	McGraw-Hill	ISBN 978-0-07- 338064-3

J. Teaching and Learning Strategy:

Teaching activities primarily rely on the teacher-directed teaching method where the students will receive instructions on the concepts related to the course in sequential manner. Therefore, it's essential that students be present and take notes on all the lecture.

The learning process consists of attending short tutorial sessions, regular tutorial sessions, and quiz/midterm exam script-checking sessions.

Short Tutorial Sessions: These sessions will be held in a classroom setting, where students will be given a problem to solve after the related concepts have been adequately addressed. Students are expected to actively engage in solving the problem to assess their own understanding, with an emphasis on identifying gaps in their knowledge. They are strongly encouraged to consult with one another in their efforts to find a solution.

Regular Tutorial Sessions: These sessions will be organized by the Teaching Assistant and will be conducted in person on campus. During these sessions, students will actively engage in solving problems related to various concepts. If students encounter difficulties, they are expected to seek one-on-one explanations. Peer-to-peer assistance is strongly encouraged.

Teaching Assistants are strictly instructed not to solve any problems on the whiteboard upon request unless students have demonstrated active participation in the problem-solving process. Additionally, TAs will not provide consultations on conceptual topics, as separate consultation sessions are allocated for that purpose.

This exercise aims to help students identify gaps in their understanding, address those gaps, and ultimately solidify their grasp of key concepts.

Script Checking Sessions: These sessions aim to provide feedback on different assessment activities. During script-checking sessions (SC sessions), students must bring their class notes. Feedback on exam mistakes will be provided, serving as an essential tool for enhancing topic comprehension. This approach is based on the principle that identifying mistakes highlights gaps in understanding and indicates what not to do. Recognizing these gaps provides a starting point for corrective measures to strengthen learning.

Student participation in Regular tutorial sessions and Script checking sessions will be recorded and considered a component of their overall evaluation.

K. Assessment and Evaluation:

Assessment Strategy

During the course duration, marking policy and guidance for students are mentioned as follows. These policies will be followed strictly and can only be amended as per the course instructor only.

➤ To assess the understanding and knowledge of the students, a total of 4 quizzes will be taken, spread out evenly over the semester. Best 3 out of 4 quizzes will be counted. No make-up quizzes will be taken.

- ➤ One mid-term exam and one final exam will be taken with the duration of 1 hour and 2 hours, respectively. Students will be assessed on their level of attainment of CO1 and CO2 through these exams.
- > Students will be given a design project in order to assess their ability to design and analyze an electronic circuit that meets the required specifications under certain constraints (CO3). Students will be conducting the project in groups for a certain number of weeks during the semester period.
- ➤ All graded work except the design project must be done independently. Plagiarism is strictly prohibited. Depending on the severity of the plagiarism, disciplinary action may be taken against the students involved in plagiarism.

CO Assessment Plan:

Assessment Tools	Course Outcomes					
	CO1	CO2	CO3	CO4	CO5	
Assignment	√	√				
Quiz	✓	✓				
Design Project			√			
Exam	✓	✓				
Lab Work (Software)					√	
Open-ended Lab				√		
Lab Exam (Software)					√	

Marks distribution:

Theory:

Assessment Tools	Weightage
Class Performance & Attendance	5%
Tutorial & Consultation participation	2%
Assignment	5%
Quiz	28%
Midterm Exam	20%
Final Exam	30%
Design Project	10%

Laboratory:

Assessment Tools	Weightage
Lab Attendance	5%
Lab Work (Hardware)	15%
Lab Work (Software)	10%
Lab Report	20%
Open-ended Lab	20%

Lab Exam (software,	30%
Hardware)	

Make-up Procedures:

Students are not encouraged to give make-up mid-term except under special circumstances, subject to the approval of the department.

Make-up examinations will only be allowed to the students with extreme medical condition OR death in the immediate family during the semester. (Recommendations from 30th Syndicate and 69th Academic Council, BoT approved in the 27th meeting)

Students must provide written notification prior to the exam if they are going to miss it, which will warrant the arrangement of a make-up exam. To apply for a make-up exam, students must complete the appropriate form available at the office, obtain the necessary approval, and submit the form along with the required fees to the registrar's office.

L. CO Attainment Policy:

As per the course outcome attainment policy of the Department of Electrical and Electronic Engineering

A.3: CO Perfornance Criteria and Scale					
	Performance Category	Score range			
Scale		Min	Max		
4	Exemplary	80	100		
3	Satisfactory	60	79		
2	Developing	40	59		
1	Unsatisfactory	0	39		
	Target CO attainment level (Minimum % of students in satisfactory and above level)		50		

M. Grading policy: As per Brac University grading policy.

N. Course Coordinator: Dr. Belal Bhuian

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